



#### **60V NPN MEDIUM POWER TRANSISTOR IN SOT89**

#### **Description**

This Bipolar Junction Transistor (BJT) is designed to meet the stringent requirements of automotive applications.

#### **Features**

- BV<sub>CEX</sub> > 150V
- BV<sub>CFO</sub> > 60V
- BV<sub>ECO</sub> > 6V
- I<sub>C</sub> = 5A Continuous Collector Current
- V<sub>CE(sat)</sub> < 70mV @ 1A</li>
- $R_{CE(sat)} = 48m\Omega$  for a Low Equivalent On-Resistance
- Very Low Saturation Voltages
- Excellent hFE Characteristics
- 6V Reverse Blocking Capability
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

### **Mechanical Data**

- Case: SOT89
- Case Material: Molded Plastic. "Green" Molding Compound.
   UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 63
- Weight: 0.055 grams (Approximate)

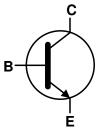
### **Applications**

- Motor Driving (including DC fans)
- Solenoid, Relay and Actuator Drivers
- DC-DC Modules
- Power Switches
- MOSFET Gate Drivers

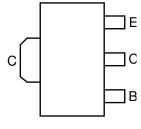
#### **SOT89**



Top View



Equivalent Circuit



Top View Pin-Out

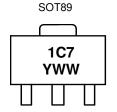
#### Ordering Information (Notes 4 & 5)

Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXTN25060BZQTA	Automotive	1C7	7	12mm	1,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen and Antimony free, "Green" and Lead-Free.
- 3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to http://www.diodes.com/quality/product\_compliance\_definitions/.
- $5.\ For\ packaging\ details,\ go\ to\ our\ website\ at\ http://www.diodes.com/products/packages.html.$

### **Marking Information**



1C7= Product Type Marking Code YWW = Date Code Marking Y = Last Digit of Year (ex: 5 = 2015) WW = Week Code (01 ~ 53)



### Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	150	V
Collector-Emitter Voltage (Forward Blocking)	V <sub>CEX</sub>	150	V
Collector-Emitter Voltage	V <sub>CEO</sub>	60	V
Emitter-Collector Voltage (Reverse Blocking)	V <sub>ECO</sub>	6	V
Emitter-Base Voltage	V <sub>EBO</sub>	7	V
Continuous Collector Current	Ic	5	Α
Base Current	I <sub>B</sub>	1	A
Peak Pulse Current	I <sub>CM</sub>	10	А

# Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
	(Note 6)		1.1		
Dawer Dissination	(Note 7)	В	1.8	W	
Power Dissipation	(Note 8)	P <sub>D</sub>	2.4		
	(Note 9)		4.46		
	(Note 6)		117		
Thermal Resistance, Junction to Ambient Air	(Note 7)	ь	68		
Thermal nesistance, Junction to Ambient All	(Note 8)	$R_{ hetaJA}$	51	°C/W	
	(Note 9)		28		
Thermal Resistance, Junction to Lead	(Note 10)	$R_{ heta JL}$	8		
Operating and Storage Temperature Range	T <sub>J,</sub> T <sub>STG</sub>	-55 to +150	°C		

### ESD Ratings (Note 11)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

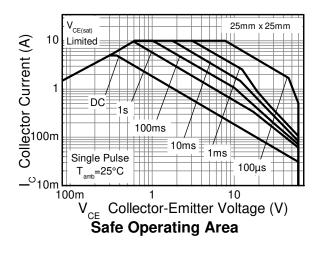
- 6. For a device mounted with the exposed collector pad on 15mm x 15mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.

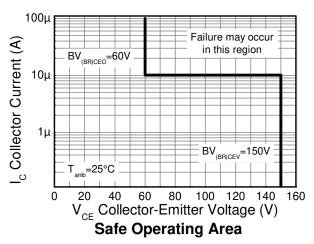
  7. Same as Note 5, except the device is mounted on 25mm x 25mm 2oz copper.
- Same as Note 5, except the device is mounted on 50mm x 50mm 2oz copper.
   Same as Note 7 measured at t<5 seconds.
- 10. Thermal resistance from junction to solder-point (on the exposed collector pad).

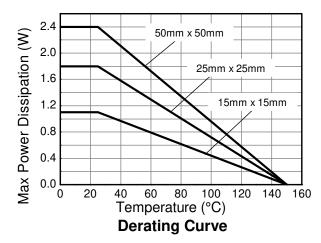
  11. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



# **Thermal Characteristics and Derating Information**

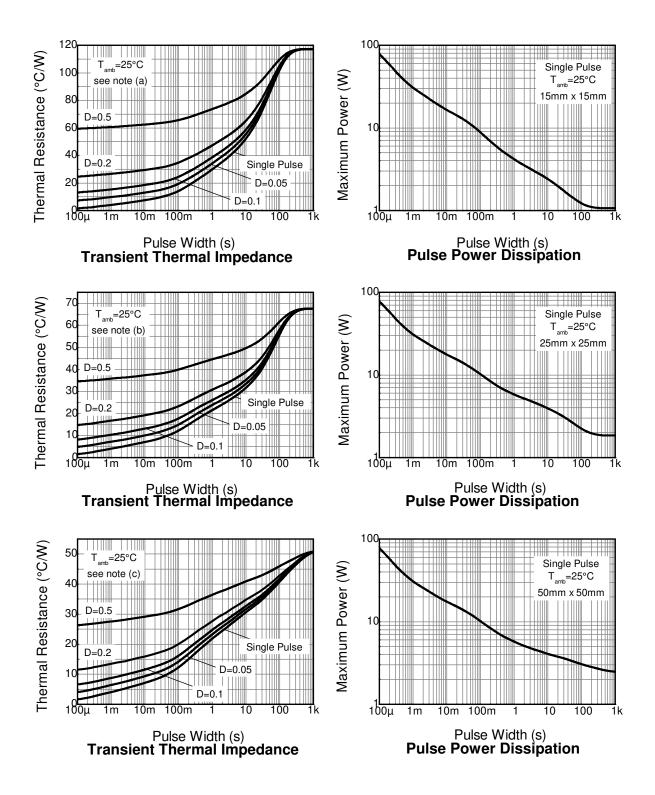








#### Thermal Characteristics and Derating Information (continued)





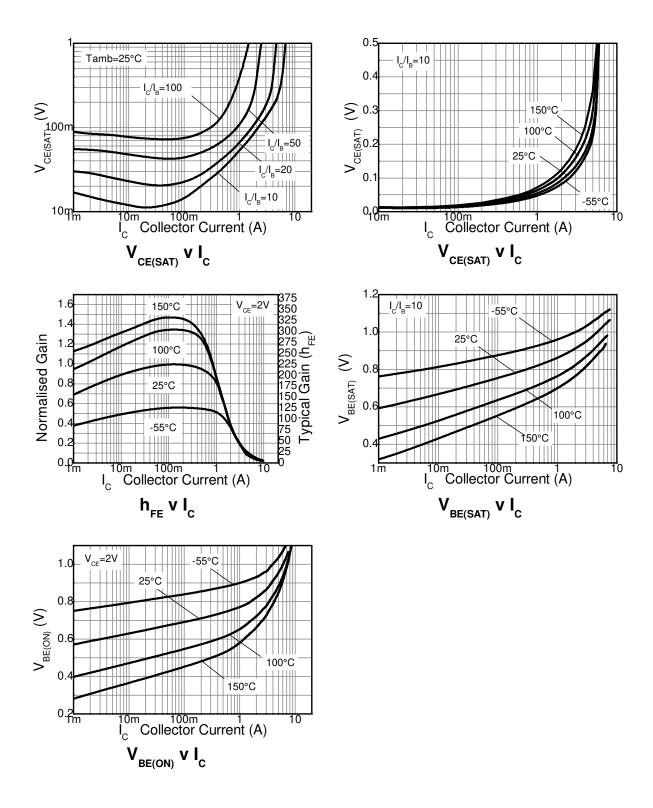
# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	150	190	_	V	$I_C = 100\mu A$
Collector-Emitter Breakdown Voltage (Forward Blocking)	BV <sub>CEX</sub>	150	190	_	٧	$I_C$ = 100μA, $R_{BE} \le 1$ k $\Omega$ or -1V < $V_{BE}$ <0.25V
Collector-Emitter Breakdown Voltage (Note 12)	BV <sub>CEO</sub>	60	80	_	٧	$I_C = 10mA$
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	7	8.0	_	V	$I_E = 100 \mu A$
Emitter-Collector Breakdown Voltage (Reverse Blocking)	BV <sub>ECX</sub>	6	8	_	V	$\begin{split} I_E &= 100 \mu A, \ R_{BC} \leq 1 k \Omega \ or \\ &< 0.25 V > V_{BC} > 0.25 V \end{split}$
Emitter-Collector Breakdown Voltage (Base Open)	BV <sub>ECO</sub>	6	7	_	V	$I_E = 100 \mu A$
Collector-Base Cutoff Current	I <sub>CBO</sub>	_	<1	50 20	nA μA	V <sub>CB</sub> = 120V V <sub>CB</sub> = 120V, T <sub>A</sub> = +100°C
Collector-Emitter Cutoff Current	ICEX	_	_	100	nA	$V_{CE}$ = 120V, $R_{BE} \le 1k\Omega$ or $-1V < V_{BE} < 0.25V$
Emitter-Base Cutoff Current	I <sub>EBO</sub>	_	<1	50	nA	$V_{EB} = 5.6V$
Collector-Emitter Saturation Voltage (Note 12)	V <sub>CE(sat)</sub>	_	55 70 185 240	70 90 230 305	mV	$I_C = 1A$ , $I_B = 100mA$ $I_C = 1A$ , $I_B = 50mA$ $I_C = 4A$ , $I_B = 400mA$ $I_C = 5A$ , $I_B = 500mA$
Base-Emitter Saturation Voltage (Note 12)	V <sub>BE(sat)</sub>	_	1,020	1,100	mV	$I_C = 5A$ , $I_B = 500mA$
Base-Emitter Turn-On Voltage (Note 12)	V <sub>BE(on)</sub>	_	960	1,050	mV	$I_C = 5A$ , $V_{CE} = 2V$
DC Current Gain (Note 12)	h <sub>FE</sub>	100 90 45 —	200 180 90 20	300 — — —	l	$\begin{split} I_C &= 10 mA, \ V_{CE} = 2V \\ I_C &= 1A, \ V_{CE} = 2V \\ I_C &= 2A, \ V_{CE} = 50V \\ I_C &= 5A, \ V_{CE} = 5V \end{split}$
Transitional Frequency	f <sub>T</sub>		185		MHz	$I_C = 100$ mA, $V_{CE} = 5$ V f=100MHz
Output Capacitance	C <sub>obo</sub>	_	11.5	20	pF	V <sub>CB</sub> = 10V, f=1MHz
Delay Time	t <sub>d</sub>		16		ns	.,
Rise Time	t <sub>r</sub>	_	15	_	ns	$V_{CC} = 10V$ ,
Storage Time	ts		509		ns	$I_{CC} = 500 \text{mA}$ $I_{B1} = -I_{B2} = 50 \text{mA}$
Fall Time	t <sub>f</sub>	_	57	_	ns	IDI — IDZ — OOIII/T

Note: 12. Measured under pulsed conditions. Pulse width  $\leq$  300 $\mu$ s. Duty cycle  $\leq$  2%.



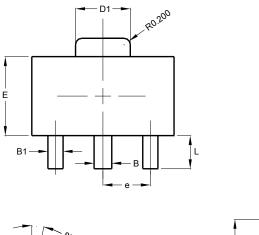
### Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

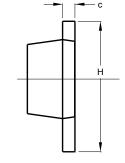


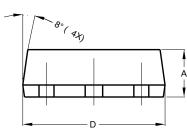


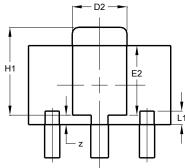
# **Package Outline Dimensions**

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.





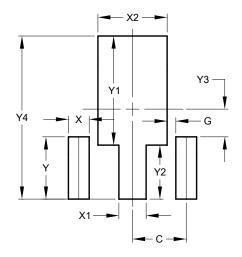




SOT89					
Dim	Min	Max	Тур		
Α	1.40	1.60	1.50		
В	0.50	0.62	0.56		
B1	0.42	0.54	0.48		
С	0.35	0.43	0.38		
D	4.40	4.60	4.50		
D1	1.62	1.83	1.733		
D2	1.61	1.81	1.71		
Е	2.40	2.60	2.50		
E2	2.05	2.35	2.20		
е		-	1.50		
Н	3.95	4.25	4.10		
H1	2.63	2.93	2.78		
L	0.90	1.20	1.05		
L1	0.327	0.527	0.427		
Z	0.20	0.40	0.30		
All Dimensions in mm					

# Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)		
С	1.500		
G	0.244		
Х	0.580		
X1	0.760		
X2	1.933		
Y	1.730		
Y1	3.030		
Y2	1.500		
Y3	0.770		
Y4	4.530		



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